SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 5145, REV. B

SILICON SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	Vrwm	-	45	V
Max. Average Forward Current	IF(AV)	50% duty cycle, rectangular wave form	15	A
Max. Peak One Cycle Non- Repetitive Surge Current	IFSM	8.3 ms, half Sine wave	280	A
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3.0 \text{ A}, L = 4.4 \text{ mH}$	20	mJ
Repetitive Avalanche Current	lar	I _{AS} decay linearly to 0 in 1 μ s f limited by T _J max V _A =1.5V _R	3.0	A
Maximum Thermal Resistance	R _{θJC}	(Junction to Mounting Surface, Cathode)	1.7	°C/W
Max. Junction Temperature	TJ	-	-65 to +175	°C
Max. Storage Temperature	T _{stg}	-	-65 to +175	°C

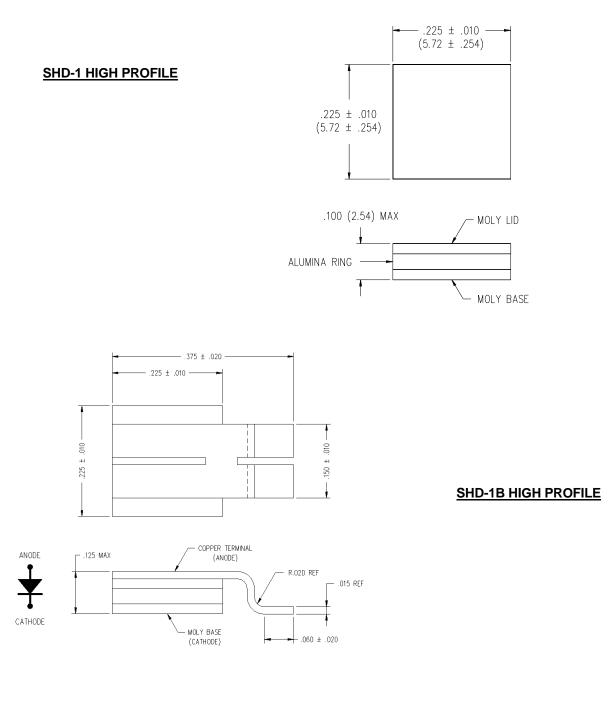
Electrical Characteristics

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 15A, Pulse, T _J = 25 °C	0.73	V
	VF2	@ 15A, Pulse, T _J = 125 °C	0.66	V
Max. Reverse Current	I _{R1}	$@V_R = 45V$, Pulse,	2	mA
		T _J = 25 °C		
	I _{R2}	$@V_{R} = 45V, Pulse,$	15	mA
		T _J = 125 °C		
Max. Junction Capacitance	Ст	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C$	800	pF
		fsig = 1MHz,		
		$V_{SIG} = 50 \text{mV} (p-p)$		

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MECHANICAL DIMENSIONS: In Inches / mm

*Dimensions shown are with solder dipping.

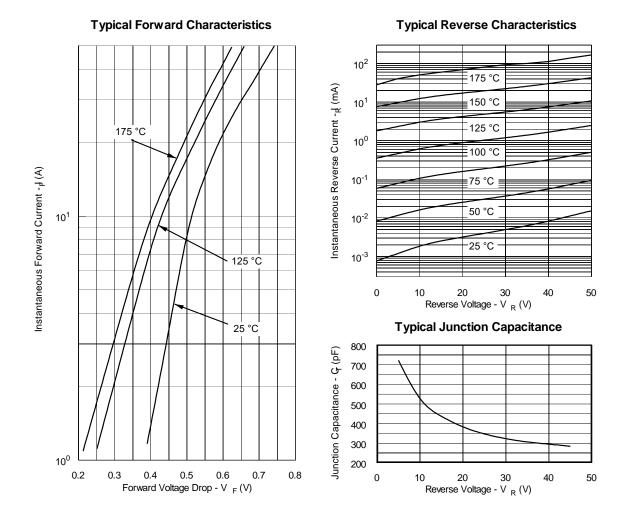


PINOUT TABLE

ТҮРЕ	PIN 1 (Base)	PIN 2
SINGLE RECTIFIER	CATHODE	ANODE
in a Surface Mount Package		

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